



PSMN7R5-60YL

N-channel 60 V, 7.5 mΩ logic level MOSFET in LFPAK56

20 November 2015

Product data sheet

1. General description

Logic level N-channel MOSFET in an LFPAK56 (Power SO8) package using TrenchMOS technology. This product is designed and qualified for use in a wide range of power supply & motor control equipment.

2. Features and benefits

- Advanced TrenchMOS provides low $R_{DS(on)}$ and low gate charge
- Logic level gate operation
- Avalanche rated, 100% tested
- LFPAK provides maximum power density in a Power SO8 package

3. Applications

- Synchronous rectifier in LLC topology
- Chargers & adaptors with $V_{out} < 10$ V
- Fast charge & USB-PD applications
- Battery powered motor control
- LED lighting & TV backlight

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|--|-----|------|-----|------|
| V_{DS} | drain-source voltage | $T_j \geq 25$ °C; $T_j \leq 175$ °C | - | - | 60 | V |
| I_D | drain current | $V_{GS} = 5$ V; $T_{mb} = 25$ °C; Fig. 2 | - | - | 86 | A |
| P_{tot} | total power dissipation | $T_{mb} = 25$ °C; Fig. 1 | - | - | 147 | W |
| T_j | junction temperature | | -55 | - | 175 | °C |
| Static characteristics | | | | | | |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 10$ V; $I_D = 20$ A; $T_j = 25$ °C; Fig. 11 | - | 6 | 7.5 | mΩ |
| Dynamic characteristics | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $V_{GS} = 10$ V; $I_D = 20$ A; $V_{DS} = 48$ V; $T_j = 25$ °C; Fig. 13 ; Fig. 14 | - | 60.6 | - | nC |
| Q_{GD} | gate-drain charge | $V_{GS} = 5$ V; $I_D = 20$ A; $V_{DS} = 48$ V; $T_j = 25$ °C; Fig. 13 ; Fig. 14 | - | 9.7 | - | nC |

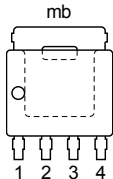
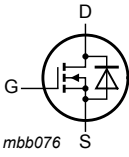
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------------------|--|---|--------|-----|-----|---------|
| Avalanche ruggedness | | | | | | |
| $E_{DS(AL)S}$ | non-repetitive drain-source avalanche energy | $I_D = 86 \text{ A}$; $V_{sup} \leq 60 \text{ V}$; $R_{GS} = 50 \Omega$; $V_{GS} = 5 \text{ V}$; $T_{j(\text{init})} = 25 \text{ }^\circ\text{C}$; unclamped; Fig. 4 | [1][2] | - | - | 76.5 mJ |

[1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[2] Refer to application note AN10273 for further information.

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-----------------------------------|--|--|
| 1 | S | source |  <p>LFAK56; Power-SO8 (SOT669)</p> |  <p><i>mbb076</i></p> |
| 2 | S | source | | |
| 3 | S | source | | |
| 4 | G | gate | | |
| mb | D | mounting base; connected to drain | | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|--------------|----------------------|---|---------|
| | Name | Description | Version |
| PSMN7R5-60YL | LFAK56; Power-SO8 | Plastic single-ended surface-mounted package (LFAK56; Power-SO8); 4 leads | SOT669 |

7. Limiting values

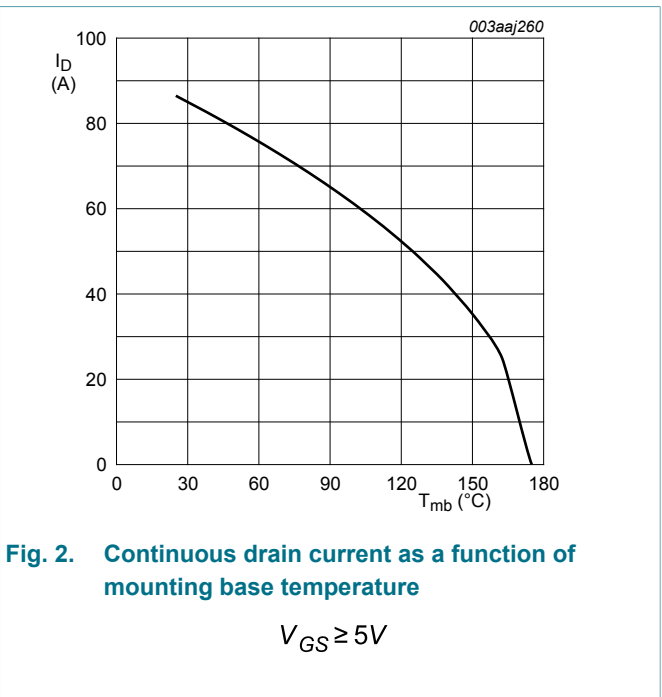
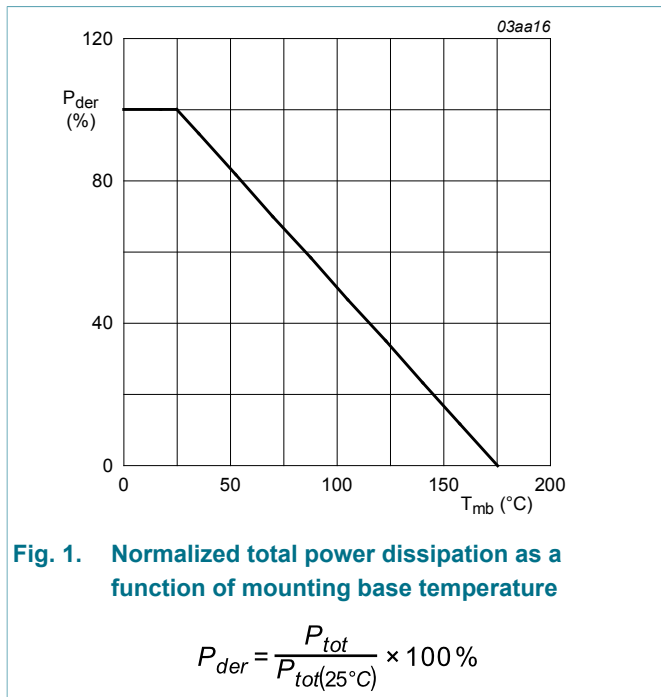
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|---|-----|-----|------|
| V_{DS} | drain-source voltage | $T_j \geq 25 \text{ }^\circ\text{C}$; $T_j \leq 175 \text{ }^\circ\text{C}$ | - | 60 | V |
| V_{DGR} | drain-gate voltage | $R_{GS} = 20 \text{ k}\Omega$ | - | 60 | V |
| V_{GS} | gate-source voltage | | -20 | 20 | V |
| P_{tot} | total power dissipation | $T_{mb} = 25 \text{ }^\circ\text{C}$; Fig. 1 | - | 147 | W |
| I_D | drain current | $T_{mb} = 25 \text{ }^\circ\text{C}$; $V_{GS} = 5 \text{ V}$; Fig. 2 | - | 86 | A |
| | | $T_{mb} = 100 \text{ }^\circ\text{C}$; $V_{GS} = 5 \text{ V}$; Fig. 2 | - | 61 | A |
| I_{DM} | peak drain current | $T_{mb} = 25 \text{ }^\circ\text{C}$; pulsed; $t_p \leq 10 \mu\text{s}$; Fig. 3 | - | 346 | A |

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------------|--|--|--------|-----|---------|
| T _{stg} | storage temperature | | -55 | 175 | °C |
| T _j | junction temperature | | -55 | 175 | °C |
| Source-drain diode | | | | | |
| I _S | source current | T _{mb} = 25 °C | - | 86 | A |
| I _{SM} | peak source current | pulsed; t _p ≤ 10 μs; T _{mb} = 25 °C | - | 346 | A |
| Avalanche ruggedness | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I _D = 86 A; V _{sup} ≤ 60 V; R _{GS} = 50 Ω; V _{GS} = 5 V; T _{j(init)} = 25 °C; unclamped; Fig. 4 | [1][2] | - | 76.5 mJ |

- [1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.
- [2] Refer to application note AN10273 for further information.



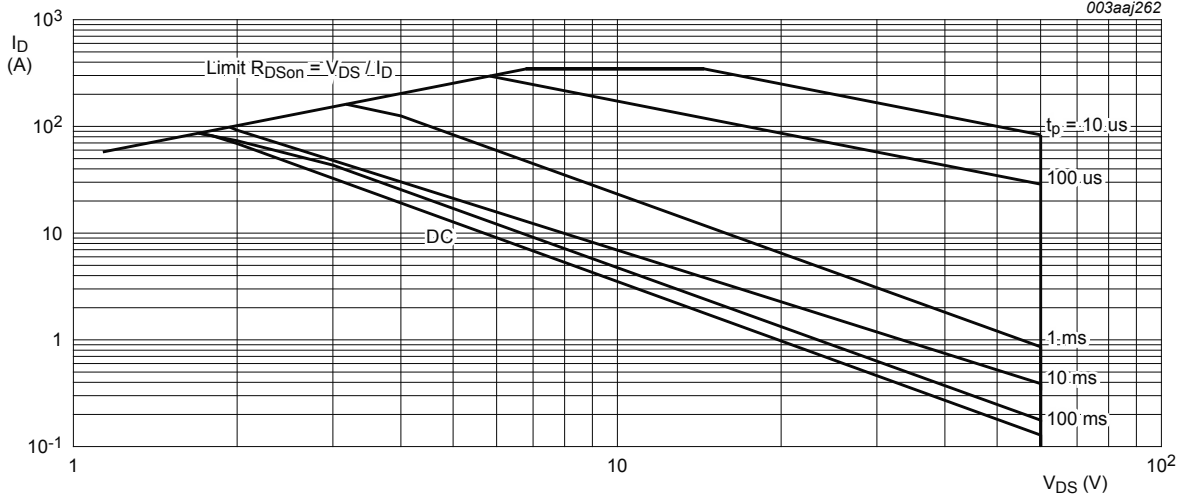


Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$T_{mb} = 25^\circ C$; I_{DM} is a single pulse

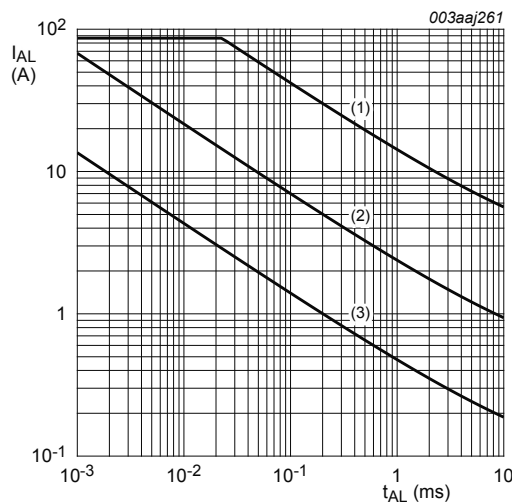


Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

(1) $T_j(i_{init}) = 25^\circ C$; (2) $T_j(i_{init}) = 150^\circ C$; (3) Repetitive Avalanche

8. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|---|------------|-----|-----|------|------|
| $R_{th(j-mb)}$ | thermal resistance from junction to mounting base | Fig. 5 | - | - | 1.02 | K/W |

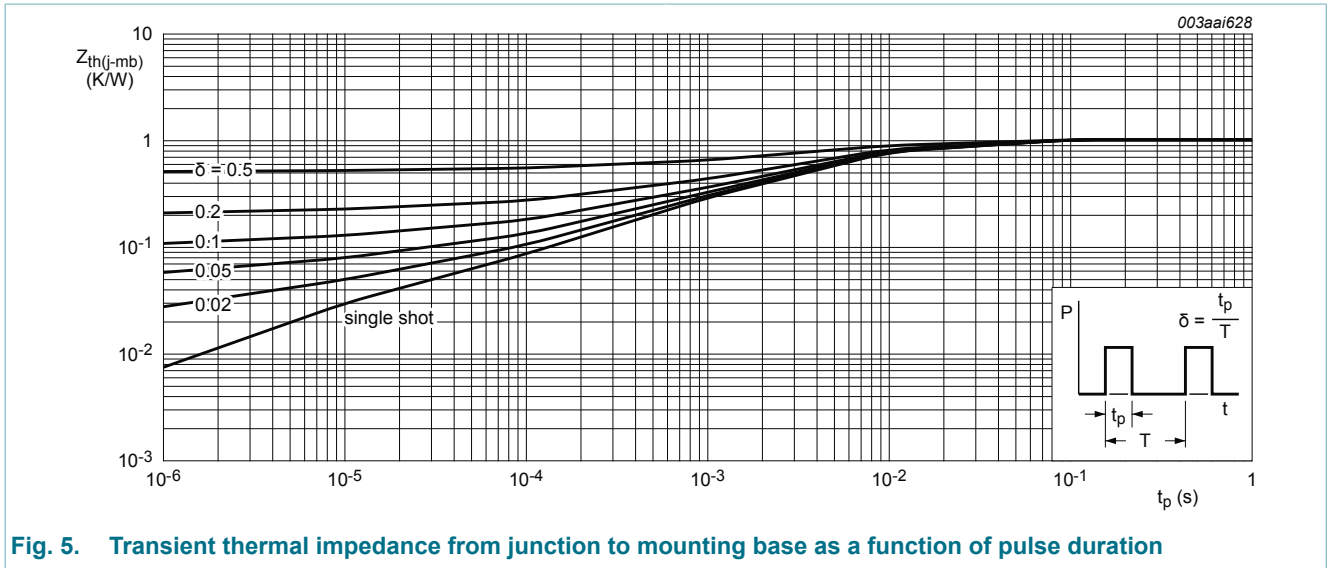


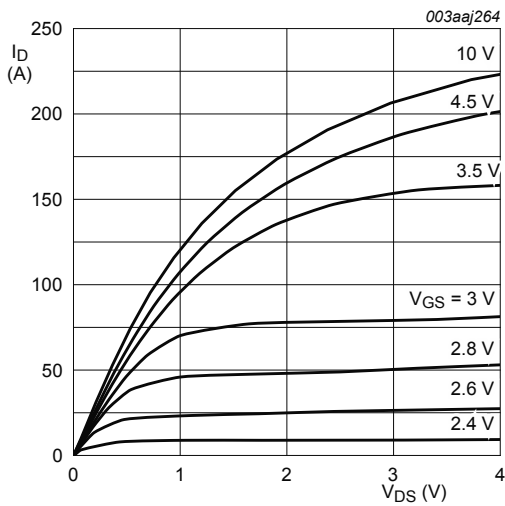
Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

9. Characteristics

Table 6. Characteristics

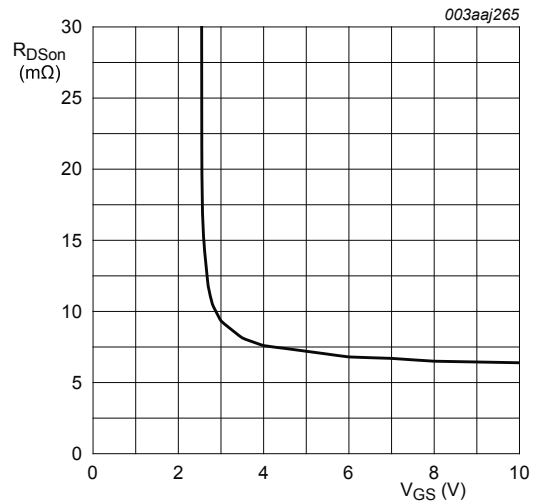
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|---|-----|------|------|---------|
| Static characteristics | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$ | 60 | - | - | V |
| | | $I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 \text{ }^\circ C$ | 54 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ C;$ Fig. 9; Fig. 10 | 1.4 | 1.7 | 2.1 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ }^\circ C;$ Fig. 9 | - | - | 2.45 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ }^\circ C;$ Fig. 9 | 0.5 | - | - | V |
| I_{DSS} | drain leakage current | $V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175 \text{ }^\circ C$ | - | - | 500 | μA |
| | | $V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$ | - | 0.05 | 10 | μA |
| I_{GSS} | gate leakage current | $V_{GS} = 16 V; V_{DS} = 0 V; T_j = 25 \text{ }^\circ C$ | - | 2 | 100 | nA |
| | | $V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25 \text{ }^\circ C$ | - | 2 | 100 | nA |
| R_{DSon} | drain-source on-state resistance | $V_{GS} = 5 V; I_D = 20 A; T_j = 25 \text{ }^\circ C;$ Fig. 11 | - | 6.8 | 8.7 | mΩ |
| | | $V_{GS} = 10 V; I_D = 20 A; T_j = 25 \text{ }^\circ C;$ Fig. 11 | - | 6 | 7.5 | mΩ |
| | | $V_{GS} = 5 V; I_D = 20 A; T_j = 175 \text{ }^\circ C;$ Fig. 12; Fig. 11 | - | - | 19.7 | mΩ |
| Dynamic characteristics | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $I_D = 20 A; V_{DS} = 48 V; V_{GS} = 5 V;$ $T_j = 25 \text{ }^\circ C;$ Fig. 13; Fig. 14 | - | 31 | - | nC |

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---------------------------|------------------------------|---|-----|------|------|------|
| | | $I_D = 20\text{ A}$; $V_{DS} = 48\text{ V}$; $V_{GS} = 10\text{ V}$; $T_j = 25\text{ °C}$; Fig. 13 ; Fig. 14 | - | 60.6 | - | nC |
| Q_{GS} | gate-source charge | $I_D = 20\text{ A}$; $V_{DS} = 48\text{ V}$; $V_{GS} = 5\text{ V}$; $T_j = 25\text{ °C}$; Fig. 13 ; Fig. 14 | - | 9 | - | nC |
| Q_{GD} | gate-drain charge | | - | 9.7 | - | nC |
| C_{iss} | input capacitance | $V_{GS} = 0\text{ V}$; $V_{DS} = 25\text{ V}$; $f = 1\text{ MHz}$; $T_j = 25\text{ °C}$; Fig. 15 | - | 3435 | 4570 | pF |
| C_{oss} | output capacitance | | - | 295 | 355 | pF |
| C_{rss} | reverse transfer capacitance | | - | 150 | 205 | pF |
| $t_{d(on)}$ | turn-on delay time | $V_{DS} = 45\text{ V}$; $R_L = 2\text{ }\Omega$; $V_{GS} = 5\text{ V}$; $R_{G(ext)} = 5\text{ }\Omega$; $T_j = 25\text{ °C}$ | - | 17 | - | ns |
| t_r | rise time | | - | 30 | - | ns |
| $t_{d(off)}$ | turn-off delay time | | - | 42 | - | ns |
| t_f | fall time | | - | 26 | - | ns |
| Source-drain diode | | | | | | |
| V_{SD} | source-drain voltage | $I_S = 20\text{ A}$; $V_{GS} = 0\text{ V}$; $T_j = 25\text{ °C}$; Fig. 16 | - | 0.82 | 1.2 | V |
| t_{rr} | reverse recovery time | $I_S = 20\text{ A}$; $di_S/dt = -100\text{ A}/\mu\text{s}$; $V_{GS} = 0\text{ V}$; $V_{DS} = 25\text{ V}$; $T_j = 25\text{ °C}$ | - | 24 | - | ns |
| Q_r | recovered charge | | - | 22.3 | - | nC |



$T_j = 25\text{ °C}$; $t_p = 300\text{ }\mu\text{s}$

Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values



$T_j = 25\text{ °C}$; $I_D = 20\text{ A}$

Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

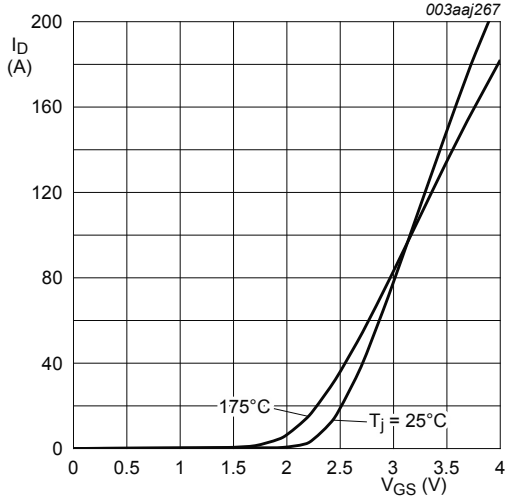


Fig. 8. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

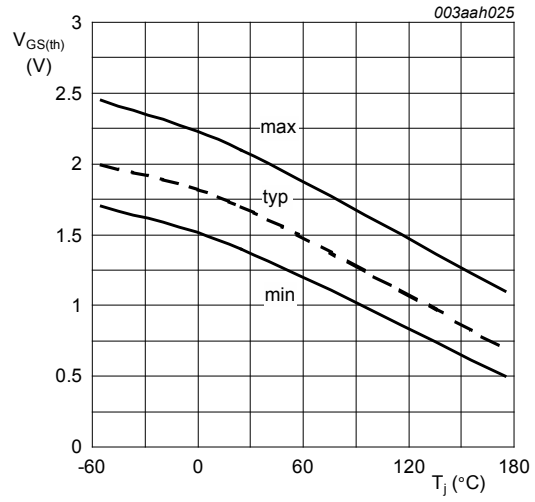


Fig. 9. Gate-source threshold voltage as a function of junction temperature

$$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$$

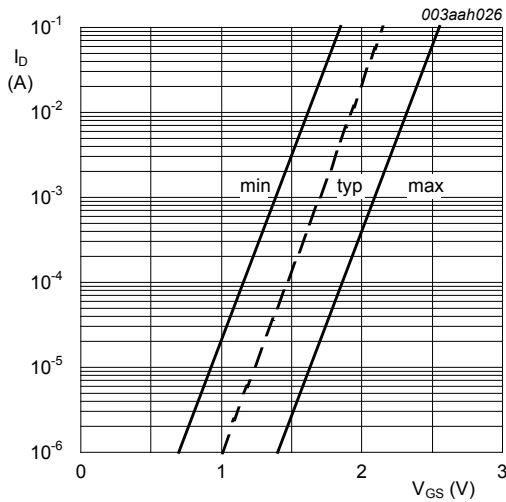
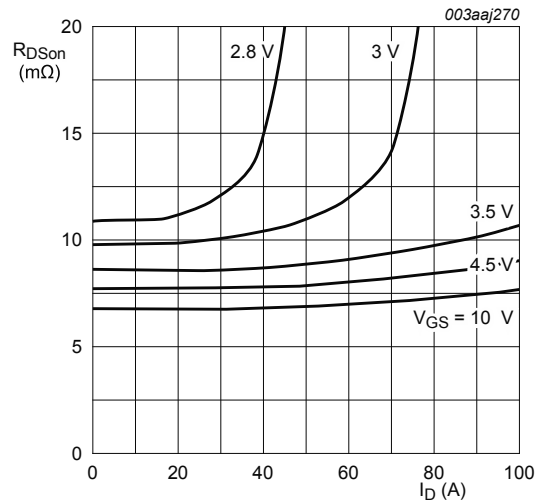


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25^\circ\text{C}; V_{DS} = 5V$$



$$T_j = 25^\circ\text{C}; t_p = 300 \mu\text{s}$$

Fig. 11. Drain-source on-state resistance as a function of drain current; typical values

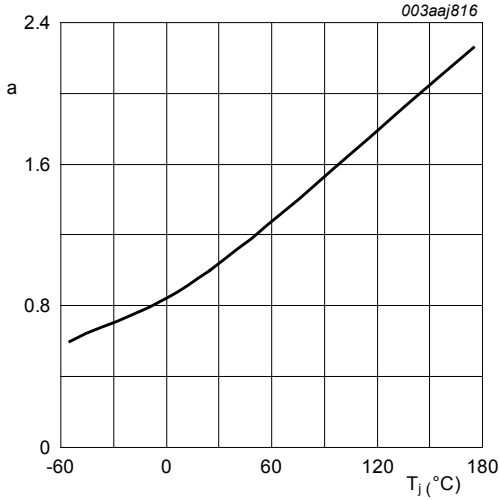


Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon}(25^{\circ}\text{C})}$$

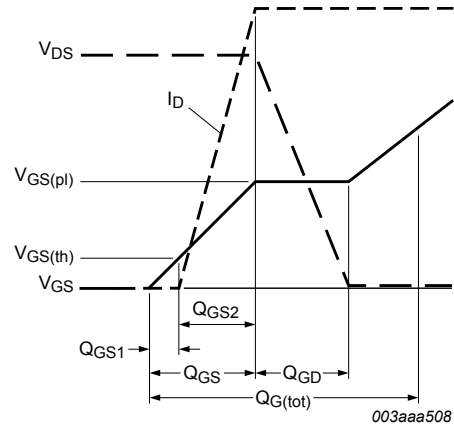


Fig. 13. Gate charge waveform definitions

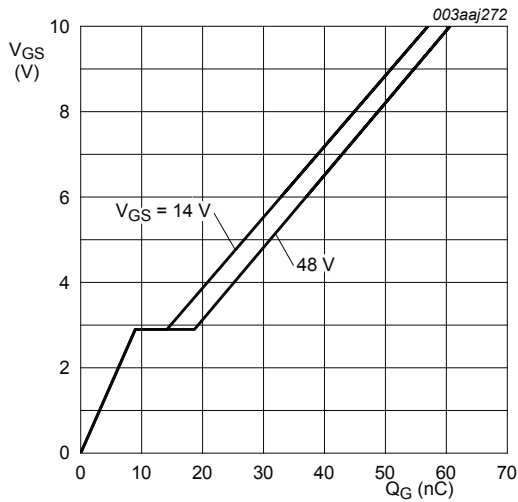


Fig. 14. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}\text{C}; I_D = 20\text{A}$$

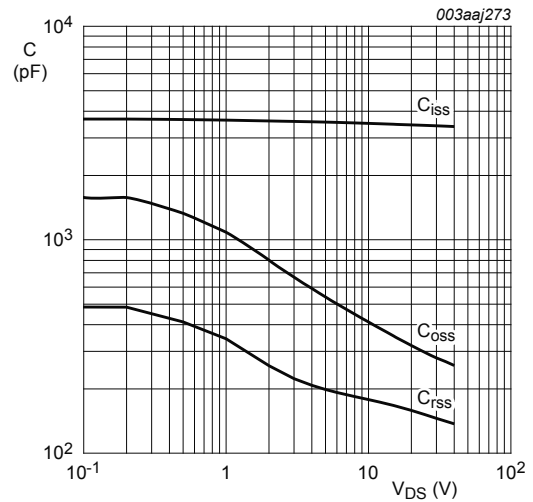


Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = 0\text{V}; f = 1\text{MHz}$$

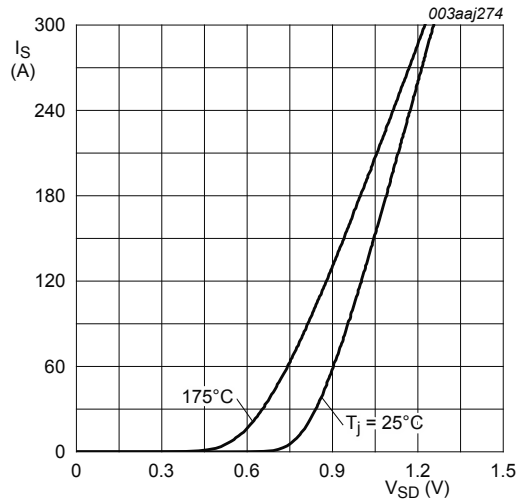


Fig. 16. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

$$V_{GS} = 0V$$

10. Package outline



Fig. 17. Package outline LPAK56; Power-SO8 (SOT669)

11. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|--------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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- [2] The term 'short data sheet' is explained in section "Definitions".
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